TRIPLE 3-INPUT POSITIVE-NAND GATES WITH OPEN-COLLECTOR OUTPUTS

DECEMBER 1983-REVISED MARCH 1988

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers and Flat Packages, and Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

description

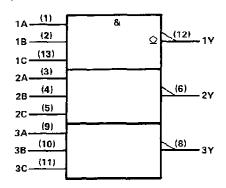
These devices contain three independent 3-input NAND gates with open-collector outputs. The open-collector outputs require pull-up resistors to perform correctly. They may be connected to other open-collector outputs to implement active-low wired-OR or active-high wired-AND functions. Open-collector devices are often used to generate higher VOH levels.

The SN5412 and SN54LS12 are characterized for operation over the full military temperature range of -55°C to 125°C. The SN7412 and SN74LS12 are characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each gate)

ll.	VPUT	S	OUTPUT
A	В	C	Y
Н	Н	н	L
L	Х	x	н
х	L	x	н
Х	Х	ᆸ	Н

logic symbol†



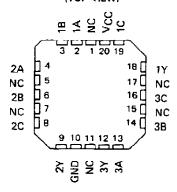
 $^{^\}dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

SN5412, SN54LS12...J OR W PACKAGE SN7412...N PACKAGE SN74LS12...D OR N PACKAGE (TOP VIEW)

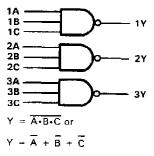
1A	ďι	U 14	VCC
1B	□ 2	13	1C
2A	□3	12	1Y
2B	□₄	11	3C
2C	□ 5	10	3B
2Y	□ 6	е	3A
GND	Ū۶	8	3Y

SN54LS12 . . . FK PACKAGE (TOP VIEW)



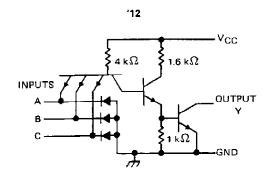
NC-No internal connection

logic diagram (positive logic)

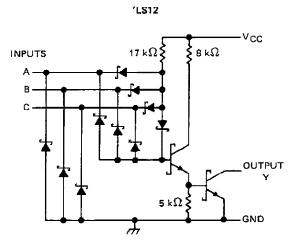


TRIPLE 3-INPUT POSITIVE-NAND GATES WITH OPEN-COLLECTOR OUTPUTS

schematics (each gate)







absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

upply voltage, V _{CC} (see Note 1)	/
nput voltage: '12 5.5 '	/
'LS12 7'	
Iff-state output voltage	
perating free-air temperature: SN54'55°C to 125°	2
\$N74'	0
torage temperature range—65°C to 150°	2

NOTE 1: Voltage values are with respect to network ground terminal.

SN5412, SN5412 TRIPLE 3-INPUT POSITIVE NAND GATES WITH OPEN COLLECTOR OUTPUTS

recommended operating conditions

		SN5412			SN7412			
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
V _{CC} Supply voltage	4.5	5	5,5	4.75	5	5,25	V	
V _{1H} High-level input voltage	2			2			V	
V _{IL} Low-level input voltage			8.0			0.8	V	
VOH High-level output voltage			5.5			5,5	V	
IOL Low-level output current			16			16	mΑ	
TA Operating free-air temperature	- 55		125	0		70	∘c	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS [†]	SN5412	SN7412	
PANAMICIES	TEST CONDITIONS,	MIN TYPI MAX	MIN TYPI MAX	UNIT
VIK	VCC = MIN, II = -12 mA	-1.5	- 1.5	٧
la	V _{CC} = MIN, V _{IL} = 0.8 V, V _{OH} = 5.5 V		0.25	A
I _{ОН}	$V_{CC} = MIN$, $V_{IL} = 0.7 \text{ V}$, $V_{OH} = 5.5 \text{ V}$	0.25		mA
VOL	VCC = MIN, VIH = 2 V, IOL = 16 mA	0.2 0.4	0.2 0.4	٧
Jr .	V _{CC} = MAX, V _I = 5.5 V	ī	1	mΑ
ін	$V_{CC} = MAX$, $V_I = 2.4 V$	40	40	μА
	$V_{CC} = MAX$, $V_I = 0.4 V$	-1.6	-1.6	mA
^I ССН	$V_{CC} = MAX$, $V_I = 0$	3 6	3 6	mΑ
¹ CCL	$V_{CC} = MAX$, $V_I = 4.5 V$	9 16.5	9 16.5	mA

[†]For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, VCC = 5 V, TA = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	UNIT
^t PLH	A, B or C	· ·	R _L = 4 k(),	CL = 15 pF		35	45	ns
tPHL.	,1, 2 OI G	<u>'</u>	R _L = 400 Ω,	CL = 15 pF		8	15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

 $^{^{\}ddagger}$ All typical values are at V_{CC} = 5 V, T_A = 25 °C.

SN54LS12, SN74LS12 TRIPLE 3-INPUT POSITIVE-NAND GATES WITH OPEN-COLLECTOR OUTPUTS

recommended operating conditions

		SN54LS12			\$N74LS12			
	MIN	NOM	мах	MIN	NOM	MAX	UNIT	
VCC Supply voltage	4.5	5	5,5	4.75	5	5.25	V	
VIH High-level input voltage	2			2			٧	
VIL · Low-level input voltage			0.7			0.8	V	
VOH High-level output voltage			5.5			5.5	٧	
IOL Low-level output current			4			. 8	mΑ	
TA Operating free-air temperature	– 55		125	0		70	°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				SN54LS	12	SN74LS12			UNIT	
PARAMETER		TEST CONDITIONS †		MIN	TYP‡	MAX	MIN	TYP\$	MAX	UNII
VIK	V _{CC} = MIN,	I ₁ = - 18 mA				- 1.5			- 1.5	V
ГОН	V _{CC} = MIN,	V _{IL} = MAX,	V _{OH} = 5.5 V			0.1			0.1	mA
	V _{CC} = MIN,	V _{1H} = 2 V,	I _{OL} = 4 mA		0.25	0.4		0.25	0.4	V
VOL	V _{CC} = MIN,	V _{IH} = 2 V,	IOL = 8 mA					0.35	0.5	ľ
11	V _{CC} = MAX,	V = 7 V				0.1			0.1	mA
Чн	V _{CC} = MAX,	V _I = 2.7 V				20			20	μА
ηL	V _{CC} = MAX,	V = 0.4 V				- 0.4			- 0.4	mA
іссн	V _{CC} = MAX,	V(= 0			- 0.7	1.4		0,7	1.4	mA
¹ CCL	V _{CC} = MAX,	V _I = 4.5 V			1,8	3.3		1.8	3,3	mΑ

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. ‡ All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM	то	TEST CONDITIONS	MIN TYP	MAX	UNIT
raname: en	(INPUT)	(OUTPUT)				
tPLH	A, B or C		R _L = 2 kΩ, C _L = 15 pF	17	32	ns
tPHL.	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	•	NE - 2 232, SE 1 1 3 PI	15	28	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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